

RoHS

COMPLIANT

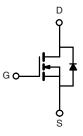
Automotive N-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	60			
$R_{DS(on)}(\Omega)$ at V_{GS} = 10 V	0.031			
$R_{DS(on)}\left(\Omega\right)$ at V_{GS} = 4.5 V	0.045			
I _D (A)	23			
Configuration	Single			
Package	TO-252			



FEATURES

- TrenchFET[®] power MOSFET
- 100 % R_g and UIS tested
- AEC-Q101 qualified d
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \text{ °C}$, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage	V _{GS}	± 20	V		
Continuous Drain Current	T _C = 25 °C	- I _D	23		
Continuous Drain Current	T _C = 125 °C		13		
Continuous Source Current (Diode Conduction) ^a		I _S	30	А	
Pulsed Drain Current ^b		I _{DM}	90		
Single Pulse Avalanche Current	rent		20		
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	20	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	P _D	37	W	
Maximum Fower Dissipation ~	T _C = 125 °C	۲D	12	٧V	
Operating Junction and Storage Temperature Rar	T _J , T _{stg}	-55 to +175	С°		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	50	°C/W	
Junction-to-Case (Drain)		R _{thJC}	4	0/00	

- Notes
- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.

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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static							1	
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA		60	-	-		
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	- V _{GS} , I _D = 250 μΑ	1.5	2.0	2.5	V	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1.0		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 175 °C	-	-	250		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	30	-	-	Α	
		$V_{GS} = 10 V$	I _D = 15 A	-	0.024	0.031		
Durin Source On State Desistance a		$V_{GS} = 10 V$	I _D = 15 A, T _J = 125 °C	-	-	0.055		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 15 A, T _J = 175 °C	-	-	0.070	Ω	
		$V_{GS} = 4.5 V$	I _D = 10 A	-	-	0.045		
Forward Transconductance ^b	g fs	V _{DS} = 15 V, I _D = 15 A		-	25	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	674	845	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	144	180		
Reverse Transfer Capacitance	C _{rss}			-	55	70		
Total Gate Charge ^c	Qg			-	16	24		
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 10 \text{ V}$	$V_{DS} = 30 \text{ V}, I_D = 23 \text{ A}$	-	4	-	nC	
Gate-Drain Charge ^c	Q _{gd}			-	3	-	1	
Gate Resistance	Rg	f = 1 MHz		0.5	1.4	3.3	Ω	
Turn-On Delay Time ^c	t _{d(on)}			-	6	9		
Rise Time ^c	t _r	$\label{eq:VDD} \begin{array}{l} V_{DD}=30~V,~R_L=1.3~\Omega,\\ I_D\cong23~A,~V_{GEN}=10~V,~R_g=1~\Omega \end{array}$		-	8	12	- ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	14	21		
Fall Time ^c	t _f			-	3	5		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	90	Α	
Forward Voltage	V _{SD}	I _F = 15 A, V _{GS} = 0 V		_	0.9	1.5	V	

Notes

a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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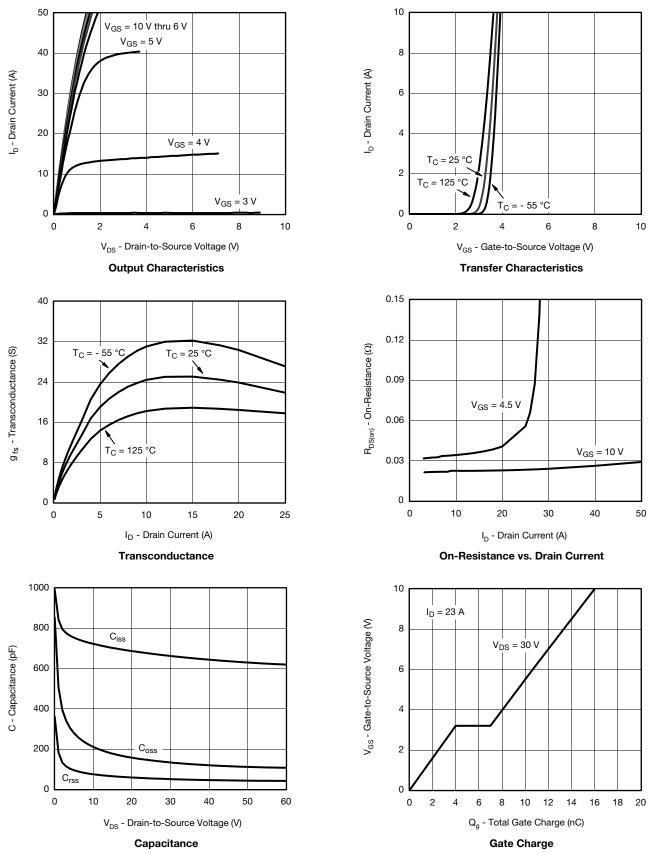
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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



S15-1873-Rev. C, 10-Aug-15

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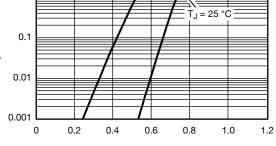
Document Number: 68869

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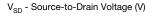
1

100

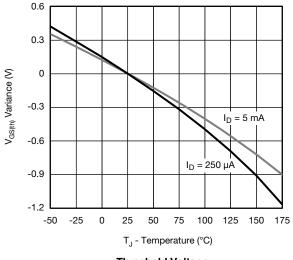
10



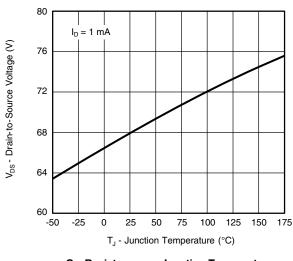
T_J = 150 °C



Source Drain Diode Forward Voltage







On-Resistance vs. Junction Temperature

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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

 $V_{GS} = 10 V$

T_J = 150 °C

T_J = 25 °C

10

8

T_J - Junction Temperature (°C) **On-Resistance vs. Junction Temperature**

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2.5

2.1

1.7

1.3

0.9

0.5

0.25

0.20

0.15

0.10

0.05

0

0

2

4

6

V_{GS} - Gate-to-Source Voltage (V)

On-Resistance vs. Gate-to-Source Voltage

 $R_{DS(on)}$ - On-Resistance (Ω)

-25 -50

0 25 50 75 100 125 150 175

R_{DS(on)} - On-Resistance (Normalized)

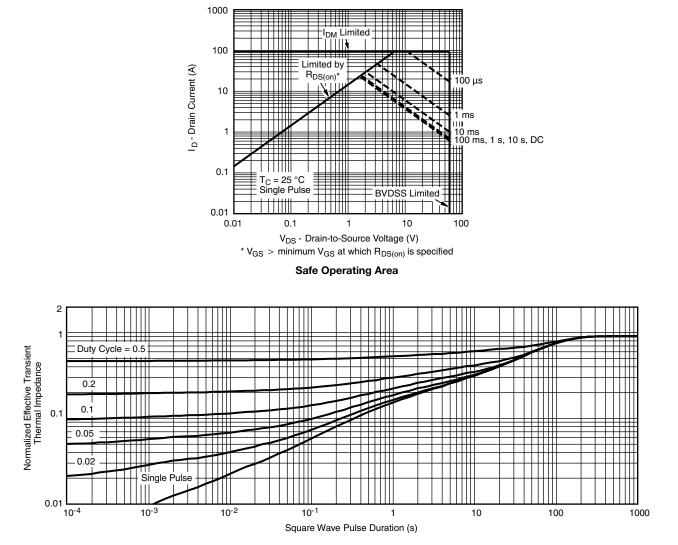
 $I_{D} = 15 \text{ A}$

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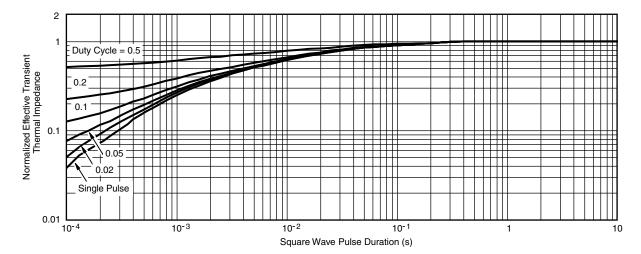
THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?68869.



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REVISION	HISTORY ^a	
REVISION	DATE	DESCRIPTION OF CHANGE
С	04-Aug-15	Revised R _g minimum limit

Note

a. As of April 2014





Е b3 Ľ Δ ŝ b2 e1 Б E1

C2 т gage plane height (0.5 mm)

-C

- A1

TO-252AA Case Outline

	MILLIMETERS		INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
А	2.18	2.38	0.086	0.094
A1	-	0.127	-	0.005
b	0.64	0.88	0.025	0.035
b2	0.76	1.14	0.030	0.045
b3	4.95	5.46	0.195	0.215
С	0.46	0.61	0.018	0.024
C2	0.46	0.89	0.018	0.035
D	5.97	6.22	0.235	0.245
D1	4.10	-	0.161	-
Е	6.35	6.73	0.250	0.265
E1	4.32	-	0.170	-
Н	9.40	10.41	0.370	0.410
е	2.28	2.28 BSC 0.090 BSC		
e1	4.56	BSC	0.180 BSC	
L	1.40	1.78	0.055	0.070
L3	0.89	1.27	0.035	0.050
L4	-	1.02	-	0.040
L5	1.01	1.52	0.040	0.060
ECN: T13-0592-Rev. A, 02-Sep-13 DWG: 6019				

Note

• Dimension L3 is for reference only.





RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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Revision: 01-Jan-2024